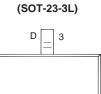
N-Channel 100 V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	R _{DS(on)} (mΩ)(Typ.)	I _D (A) ^a	Q _g (Typ.)		
100	250 at V _{GS} = 10 V	0	9 nC		
100	275 at V _{GS} = 4.5 V	2			



1 2 G s

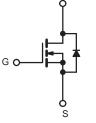
Top View

FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested
- Material categorization

APPLICATIONS

- DC/DC Converters
- · Load Switch
- LED Backlighting in LCD TVs



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N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T	A = 25 °C, unless our	ierwise noted)			
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage	V _{DS}	100	V		
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current ($T_1 = 150 \text{ °C}$)	T _C = 25 °C	I _D	2		
	T _C = 70 °C	טי	1.5	A	
Pulsed Drain Current		I _{DM}	6.5		
Single-Pulse Avalanche Energy	E _{AS}	2.5	mJ		
	T _C = 25 °C		2.2		
Maximum Power Dissipation	T _C = 70 °C	P _D	1.4	W	
	T _A = 25 °C	'D	1.1 ^{b,c}		
	T _A = 70 °C	1	0.71 ^{b,c}		
Operating Junction and Storage Temperature Range		T _J , T _{stq}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient b,d	t ≤ 10 s	R _{thJA}	110	113	°C/W	
Maximum Junction-to-Case	Steady State	R _{thJC}	50	56.8		

Notes:

a. Based on T_C = 25 °C. b. Surface mounted on 1" x 1" FR4 board.

d. Maximum under steady state conditions is 166 °C/W.





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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static					·	
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \ \mu A$	100			V
Gate-Source Threshold Voltage	VGS(th)	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1		3	V
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 100 V, V _{GS} = 0 V			1	μA
		V _{DS} = 80 V, V _{GS} = 0 V, T _J = 55 °C			10	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 4.5 \text{ V}$	2			Α
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V, I _D = 1.5 A		250 355		
		V _{GS} = 4.5 V, I _D = 1.5 A		275	310	mΩ
Forward Transconductance ^a	9 _{fs}	V _{DS} = 20 V,I _D = 1.5 A		3		S
Dynamic ^b						
Input Capacitance	C _{iss}			350		pF
Output Capacitance	C _{oss}	V _{DS} = 50 V, V _{GS} = 0 V, f = 1 MHz		15		
Reverse Transfer Capacitance	C _{rss}			9.5		
Total Gate Charge	Q _g			9		nC
Gate-Source Charge	Q _{gs}	V _{DS} = 50 V, V _{GS} = 10 V, I _D = 1.5 A		0.75		
Gate-Drain Charge	Q _{gd}	1		2		
Gate Resistance	R _g	f = 1 MHz		3		Ω
Turn-On Delay Time	t _{d(on)}			9		
Rise Time	t _r	$V_{DD} = 50 \text{ V, R}_{L} = 39 \Omega$		13		- ns
Turn-Off DelayTime	t _{d(off)}	$I_D \cong 1.5 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{g} = 1 \Omega$		12		
Fall Time	t _f	1		8		
Drain-Source Body Diode Characterist	ics			I	1	I
Continous Source-Drain Diode Current	ا _S	T _C = 25 °C			2	A
Pulse Diode Forward Current (100 µs)	I _{SM}				6.5	
Body Diode Voltage	V _{SD}	I _S = 1 A			1.2	V
Body Diode Reverse Recovery Time	t _{rr}			23		ns
Body Diode Reverse Recovery Charge	Q _{rr}	- I _F = 1.5 A, dl/dt = 100 A/μs, T _J = 25 °C		22		nC
Reverse Recovery Fall Time	t _a	$-1F - 1.5 \text{ A}, \text{ un at } = 100 \text{ A/} \mu \text{s}, 1\text{ J} = 25 \text{ C}$		18		ns
Reverse Recovery Rise Time	t _b	7		7	1	

Notes:

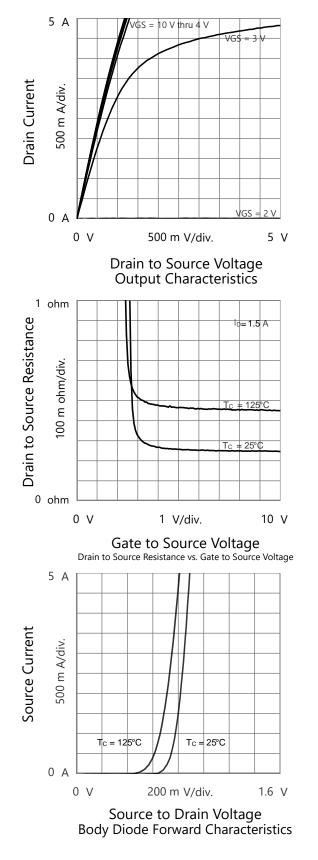
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

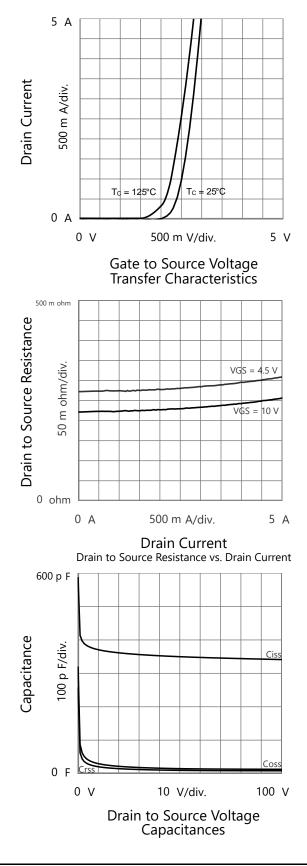
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



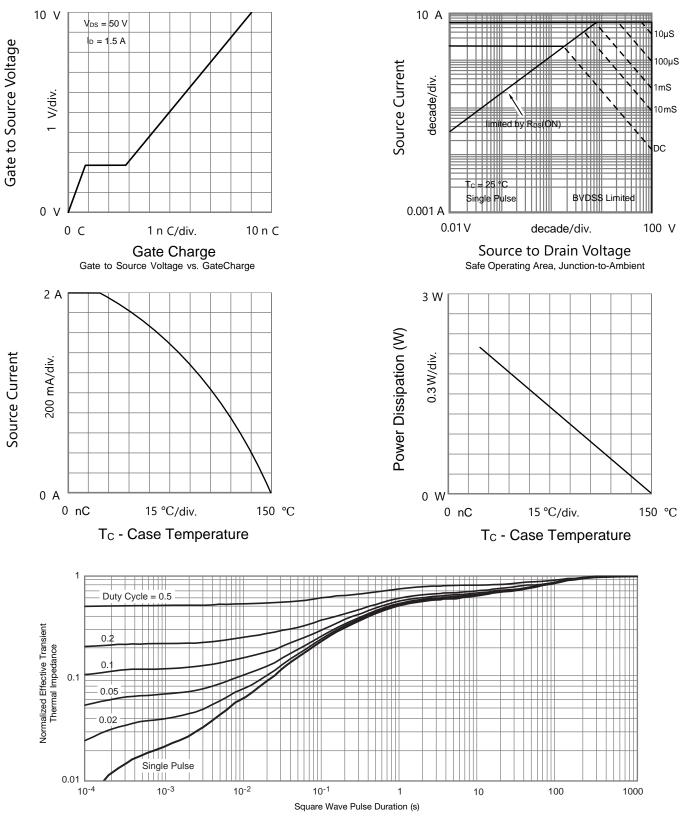
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

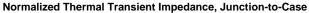






TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)







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